Quantum Mechanical & Electromagnetic Systems Modelling Lab

Reduced-Order Stochastic Testing of Interconnects Subject to Line Edge Roughness

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Outline

Motivation

Methodology

- 1. Finite-element based eigenvalue solver
- 2. Sparse grid stochastic testing
- 3. Reduced-order stochastic testing

Examples

Conclusions





Motivation

Line edge roughness

Higher operating frequencies & increased heterogenous integration causes stronger influence on physical phenomena

Line edge roughness (LER) is irregular profile of conductors owing to production process

Impact becomes stronger due to more developed skin effect

Affects important characteristics such as

- Propagation constant
- Attenuation
- Mode profile

Need for accurate, full-wave modeling



Fabricated



Attenuation [1]





[1] H. Braunisch et al. ECTC 2014

Motivation

Line edge roughness

LER is a stochastic process ightarrow stochastic analysis required

Brute-force methods such as Monte Carlo (MC) require unwieldy number of runs

Sparse techniques strongly reduce calls to full-wave solver

Every call solves costly matrix problem

GOAL: Reduce total calculation time by combining sparse grid stochastic testing and model order reduction









Methodology



Full-wave solver

Task: Compute propagation constant β of interconnect cross-section

Finite element method (FEM) solver with hierarchical basis functions

Roughness realized by displacing every node randomly according to a multivariate Gaussian distribution



Propagation constant β obeys quadratic eigenvalue problem $\left[\overline{\overline{M}}\beta^2 + \overline{\overline{C}}\beta + \overline{\overline{K}}\right]\mathbf{v} = 0$

Convert into a linear eigenvalue problem $\overline{\overline{A}}\mathbf{x} = \beta \overline{\overline{B}}\mathbf{x}$ of dimension $2n \times 2n$

Solve for many realizations of the waveguide, e.g., using MC => very expensive!!



n : number of basis functions

zoom

$N_{ m RV}$: number of random variables



Polynomial chaos expansion (PCE) + sparse-grid stochastic testing (ST)

Propagation constant modeled by a polynomial chaos expansion

$$\beta(\boldsymbol{\xi}) \approx \sum_{k=0}^{K} a_k \phi_k(\boldsymbol{\xi})$$

 ϕ_k : orthonormal polynomial $\boldsymbol{\xi}$: random variables vector

Task: Compute expansion coefficients a_k

Stochastic testing: select K + 1 interesting samples ξ_i , compute $\beta(\xi_i)$, and solve matrix equation

$$\begin{bmatrix} \beta(\boldsymbol{\xi}_0) \\ \vdots \\ \beta(\boldsymbol{\xi}_K) \end{bmatrix} = \begin{bmatrix} \phi_0(\boldsymbol{\xi}_0) & \dots & \phi_K(\boldsymbol{\xi}_0) \\ \vdots & \ddots & \vdots \\ \phi_0(\boldsymbol{\xi}_K) & \dots & \phi_K(\boldsymbol{\xi}_K) \end{bmatrix} \begin{bmatrix} a_0 \\ \vdots \\ a_K \end{bmatrix}$$

Selecting $\boldsymbol{\xi}_i$?

Node picking algorithm [2] on quadrature-based grid







Sparse (Smolyak) grid





Reduced-order ST

For every $\boldsymbol{\xi}_i$ (i.e., K+1 instances), the $2n \times 2n$ eigenvalue problem has to be solved:

$$\overline{\overline{A}}\mathbf{x} = \beta \overline{\overline{B}}\mathbf{x} \qquad \qquad \mathbf{\overline{A}} \qquad \qquad \mathbf{\overline{A}}$$

BUT: some information is recyclable between every instance ξ_i

Exploit redundancy in solving the matrix equation Project onto smaller space through projection matrix $\overline{\overline{Q}}$ to get $m \times m$ matrix equation $m \ll 2n$

$$\overline{\overline{A}}'\mathbf{x}' = \beta'\overline{\overline{B}}'\mathbf{x}' \qquad \mathbf{\overline{X}} \qquad \mathbf{\overline{X}}$$

Task: Construct $\overline{\overline{Q}}$

Base set of $N_{\rm RV} + 1$ samples ξ_i : the nominal configuration ξ_0 and one realization per axis of the grid (with highest weight) Calculate the $N_{\rm RV} + 1$ full-system solutions and store corresponding eigenvectors \mathbf{x}_i Use \mathbf{x}_j to construct the orthonormal basis vectors (columns of \overline{Q})

n: number of basis functions



Constructing Q







Interconnect structures

Rough rectangular waveguide

TE₁₀ mode rectangular waveguide

- Correlation length: 0.5 l
- Standard deviation correlation: 0.01 *l*
- N_{RV} = 8
- # simulations = 45
- Wavenumber: 10 *l*⁻¹







Interconnect structures

Boxed microstrip

Lowest propagating mode microstrip

- Correlation length: 0.1 mm
- Standard deviation correlation: 1 µm
- N_{RV} = 13
- # simulations = 105





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Conclusions



Conclusions

Line edge roughness' effect on interconnect propagation constant

Sparse grid stochastic testing to decrease number of full-wave calls

Order reduction to lower eigenvalue problem solution time

Applied to rectangular waveguide and microstrip interconnect



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